Bulletin I27216 03/06

International
IOR Rectifier

MT..KPbF SERIES

THREE PHASE BRIDGE **Power Modules**

130 A
160 A

Features

- Package fully compatible with the industry standard INT-A-pak power modules series
- High thermal conductivity package, electrically insulated case
- Excellent power volume ratio
- 4000 V_{RMS} isolating voltage
- UL E78996 approved
- TOTALLY LEAD-FREE

Description

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

Major Ratings and Characteristics

Parameters		130MT.K	160MT.K	Units
I_O		130(160)	160(200)	A
	@T_C	85(62)	85(60)	°C
I_{FSM}	@50Hz	1130	1430	A
	@60Hz	1180	1500	A
I^2t	@50Hz	6400	10200	A^2s
	@60Hz	5800	9300	A^2s
$I^2\sqrt{t}$		64000	102000	$A^2\sqrt{s}$
V_{RRM}	range	800 to 1600		V
T_{STG}	range	-40 to 150		°C
T_J	range	-40 to 150		°C

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ T_J max. mA
130-160MT..K	80	800	900	10
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	
	160	1600	1700	

Forward Conduction

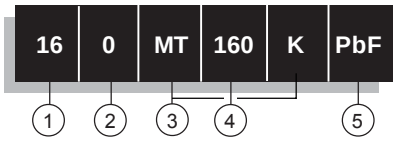
	Parameter	130MT.K	160MT.K	Units	Conditions		
I_O	Maximum DC output current	130 (160)	160 (200)	A	120° Rect conduction angle		
	@ Case temperature	85 (62)	85 (60)	°C			
I_{FSM}	Maximum peak, one-cycle forward, non-repetitive surge current	1130	1430	A	t = 10ms	No voltage reapplied	Initial T_J = T_J max.
		1180	1500		t = 8.3ms		
		950	1200		t = 10ms	100% V_{RRM} reapplied	
		1000	1260		t = 8.3ms		
I^2t	Maximum I^2t for fusing	64000	10200	A^2s	t = 10ms	No voltage reapplied	
		5800	9300		t = 8.3ms		
		4500	7200		t = 10ms	100% V_{RRM} reapplied	
		4100	6600		t = 8.3ms		
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	64000	102000	$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$	Low level value of threshold voltage	0.78	0.81	V	(16.7% x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), @ T_J max.		
$V_{F(TO)2}$	High level value of threshold voltage	0.99	1.04		(I > π x $I_{F(AV)}$), @ T_J max.		
r_{f1}	Low level value of forward slope resistance	4.59	3.52	mΩ	(16.7% x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), @ T_J max.		
r_{f2}	High level value of forward slope resistance	4.17	3.13		(I > π x $I_{F(AV)}$), @ T_J max.		
V_{FM}	Maximum forward voltage drop	1.63	1.49	V	I_{pk} = 200A, T_J = 25°C, t_p = 400µs single junction		
V_{INS}	RMS isolation voltage	4000	4000	V	T_J = 25°C, all terminal shorted f = 50Hz, t = 1s		

Thermal and Mechanical Specifications

	Parameter		130MT.K	160MT.K	Units	Conditions
T_J	Max. junction operating temperature range		-40 to 150		°C	
T_{stg}	Max. storage temperature range		-40 to 150		°C	
R_{thJC}	Max. thermal resistance, junction to case		0.16	0.12	K/W	DC operation per module
			0.93	0.73		DC operation per junction
			0.18	0.15		120° Rect conduction angle per module
			1.08	0.88		120° Rect conduction angle per junction
R_{thCS}	Max. thermal resistance, case to heatsink		0.03		K/W	Per module Mounting surface smooth, flat and greased
T	Mounting torque ± 10%	to heatsink	4 to 6		Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
		to terminal	3 to 4			
wt	Approximate weight		176		g	

Ordering Information Table

Device Code



1 - Current rating code: 13 = 130 A (Avg)
16 = 160 A (Avg)

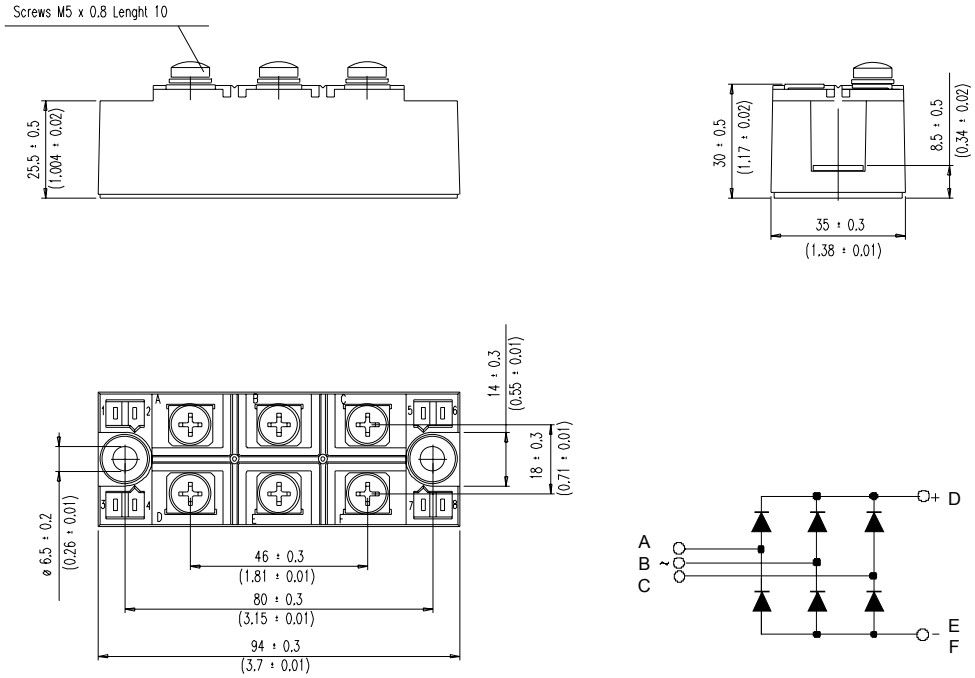
2 - Three phase diodes bridge

3 - Essential part number

4 - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings Table)

5 - PbF = Lead-Free

Outline Table (without optional barriers)



All dimensions in millimeters (inches)

NOTE: To order the Optional Hardware see Bulletin I27900